

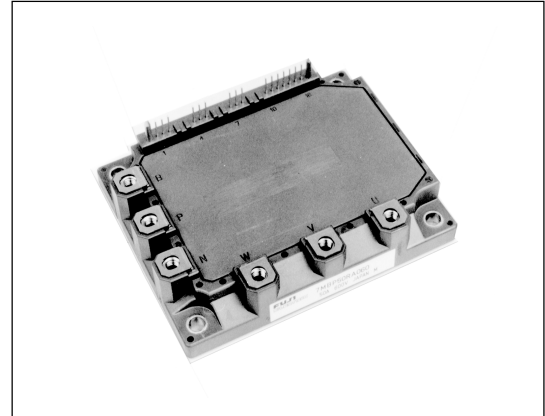
7MBP100RTB060

IPM-R3 series

600V / 100A 7 in one-package

Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



Maximum ratings and characteristics

- Absolute maximum ratings(at Tc=25°C unless otherwise specified)

Item			Symbol	Rating		Unit
				Min.	Max.	
Bus voltage (between terminal P and N)	DC		V _{DC}	0	450	V
	Surge		V _{DC(surge)}	0	500	V
	Shortoperating		V _{SC}	200	400	V
Collector-Emitter voltage			V _{CES} *1	0	600	V
Inverter	Collector current	DC	I _C	-	100	A
		1ms	I _{CP}	-	200	A
		Duty=72.3%	-I _C *2	-	100	A
	Collector power dissipation	One transistor	P _C *3	-	347	W
Brake	Collector current	DC	I _C	-	50	A
		1ms	I _{CP}	-	100	A
	Forward Current of Diode		I _F	-	50	A
	Collector power dissipation	One transistor	P _C *3	-	198	W
Input voltage of power supply for Pre-Driver			V _{CC} *4	-0.5	20	V
Input signal voltage			V _{in} *5	-0.5	V _{CC} +0.5	V
Input signal current			I _{in}	-	3	mA
Alarm signal voltage			V _{ALM} *6	-0.5	V _{CC}	V
Alarm signal current			I _{ALM} *7	-	20	mA
Junction temperature			T _j	-	150	°C
Operating case temperature			T _{OP}	-20	100	°C
Storage temperature			T _{stg}	-40	125	°C
Isolating voltage (Case-Terminal)			V _{iso} *8	-	AC2.5	kV
Screw torque	Mounting (M5)			-	3.5 *9	N·m
	Terminal (M5)			-	3.5 *9	N·m

Note

*1 : V_{CES} shall be applied to the input voltage between terminal P and U or V or W or DB, N and U or V or W or DB.

*2 : $125^{\circ}\text{C}/\text{FWD Rth(j-c)}/(\text{Ic} \times \text{V}_\text{F MAX})=125/0.665/(100 \times 2.6) \times 100=72.3\%$

*3 : $\text{Pc}=125^{\circ}\text{C}/\text{IGBT Rth(j-c)}=125/0.36=347\text{W}$ [Inverter]

$\text{Pc}=125^{\circ}\text{C}/\text{IGBT Rth(j-c)}=125/0.63=198\text{W}$ [Break]

*4 : V_{CC} shall be applied to the input voltage between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

*5 : V_{in} shall be applied to the input voltage between terminal No. 2 and 1, 5 and 4, 8 and 7, 12,13,14,15 and 10.

*6 : V_{ALM} shall be applied to the voltage between terminal No. 16 and 10.

*7 : I_{ALM} shall be applied to the input current to terminal No. 16.

*8 : 50Hz/60Hz sine wave 1 minute.

*9 : Recommendable Value : 2.5 to 3.0 N·m

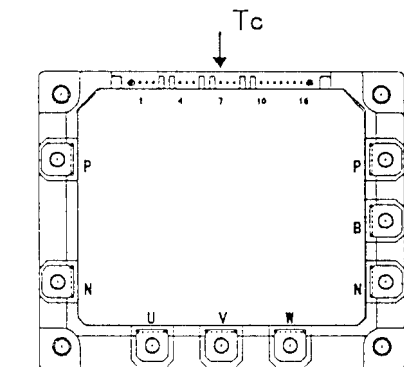


Fig.1 Measurement of case temperature

Weight

Item	Symbol	Min.	Typ.	Max.	Unit
Weight	Wt	-	450	-	g

*9 : (For 1 device, Case is under the device)

Electrical characteristics (at $T_c=T_j=25^\circ\text{C}$, $V_{cc}=15\text{V}$ unless otherwise specified.)

● **Main circuit**

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Inverter	Collector current at off signal input	I_{CES} $V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ $I_c=100\text{A}$	-	-	2.3	V
	Forward voltage of FWD	V_F $I_c=100\text{A}$	-	-	2.6	V
Brake	Collector current at off signal input	I_{CES} $V_{CE}=600\text{V}$ V_{in} terminal open.	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$ $I_c=50\text{A}$	-	-	2.2	V
	Forward voltage of Diode	V_F $-I_c=50\text{A}$	-	-	3.3	V
Turn-on time	t_{on}	$V_{DC}=300\text{V}$, $T_j=125^\circ\text{C}$	1.2	-	-	μs
Turn-off time	t_{off}	$I_c=100\text{A}$ Fig.1, Fig.6	-	-	3.6	
Reverse recovery time	t_{rr}	$V_{DC}=300\text{V}$, $I_c=100\text{A}$ Fig.1, Fig.6	-	-	0.3	
Maximum Avalanche Energy (A non-repetition)	P_{AV}	Internal wiring inductance=50nH Main circuit wiring inductance=54nH	100	-	-	mJ

● **Control circuit**

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Supply current of P-line side pre-driver(one unit)	I_{ccp}	Switching Frequency : 0 to 15kHz	-	-	18	mA
Supply current of N-line side pre-driver	I_{ccn}	$T_c=-20$ to 125°C Fig.7	-	-	65	mA
Input signal threshold voltage (on/off)	$V_{in(th)}$	ON	1.00	1.35	1.70	V
		OFF	1.25	1.60	1.95	V
Input zener voltage	V_Z	$R_{in}=20\text{k ohm}$	-	8.0	-	V
Alarm signal hold time	t_{ALM}	$T_c=-20^\circ\text{C}$ Fig.2	1.1	-	-	ms
		$T_c=25^\circ\text{C}$ Fig.2	-	2.0	-	ms
		$T_c=125^\circ\text{C}$ Fig.2	-	-	4.0	ms
Limiting resistor for alarm	R_{ALM}		1425	1500	1575	ohm

● **Protection Section** ($V_{cc}=15\text{V}$)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Over Current Protection Level of Inverter circuit	I_{OC}	$T_j=125^\circ\text{C}$	150	-	-	A
Over Current Protection Level of brake circuit		$T_j=125^\circ\text{C}$	75	-	-	A
Over Current Protection Delay time	t_{DOC}	$T_j=125^\circ\text{C}$	-	5	-	μs
SC Protection Delay time	t_{SC}	$T_j=125^\circ\text{C}$ Fig.4	-	-	8	μs
IGBT Chip Over Heating	T_{jOH}	surface of IGBT chips	150	-	-	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{jH}		-	20	-	$^\circ\text{C}$
Over Heating Protection Temperature Level	T_{COH}	$V_{DC}=0\text{V}$, $I_c=0\text{A}$, Case temperature	110	-	125	$^\circ\text{C}$
Over Heating Protection Hysteresis	T_{CH}		-	20	-	-
Under Voltage Protection Level	V_{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V_H		0.2	0.5	-	

● **Thermal characteristics**($T_c=25^\circ\text{C}$)

Item			Symbol	Min.	Typ.	Max.	Unit
Junction to Case thermal resistance	INV	IGBT	Rth(j-c)	-	-	0.36	°C/W
		FWD	Rth(j-c)	-	-	0.665	°C/W
	Brake	IGBT	Rth(j-c)	-	-	0.63	°C/W
Case to fin thermal resistance with compound			Rth(c-f)	-	0.05	-	°C/W

● **Noise Immunity** ($V_{DC}=300\text{V}$, $V_{cc}=15\text{V}$, Test Circuit Fig.5)

Item	Condition	Min.	Typ.	Max.	Unit
Common mode rectangular noise	Pulse width 1 μs , polarity \pm , 10minuets Judge : no over-current, no miss operating	± 2.0	-	-	kV
Common mode lightning surge	Rise time 1.2 μs , Fall time 50 μs Interval 20s, 10 times Judge : no over-current, no miss operating	± 5.0	-	-	kV

● **Recommendable value**

Item	Symbol	Min.	Typ.	Max.	Unit
DC Bus Voltage	V_{DC}	-	-	400	V
Operating Supply Voltage of Pre-Driver	V_{cc}	13.5	15.0	16.5	V
Screw torque (M5)	-	2.5	-	3.0	Nm

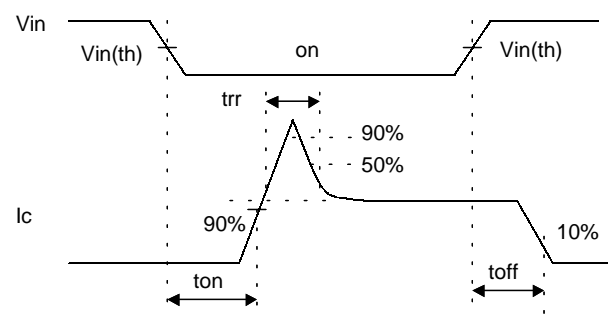
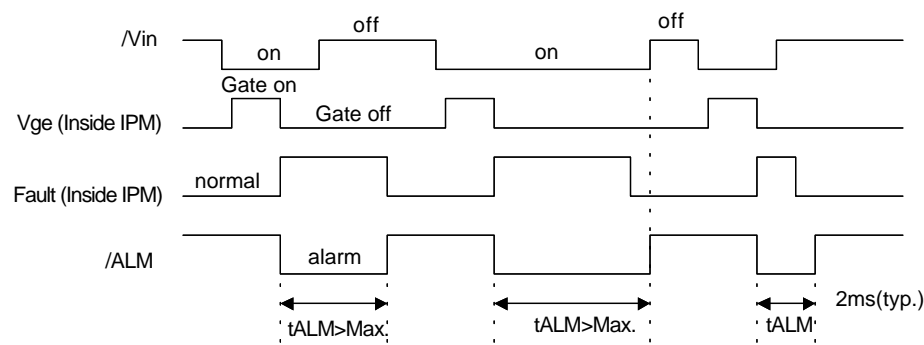


Figure 1. Switching Time Waveform Definitions



Fault : Over-current, Over-heat or Under-voltage

Figure 2. Input / Output Timing Diagram

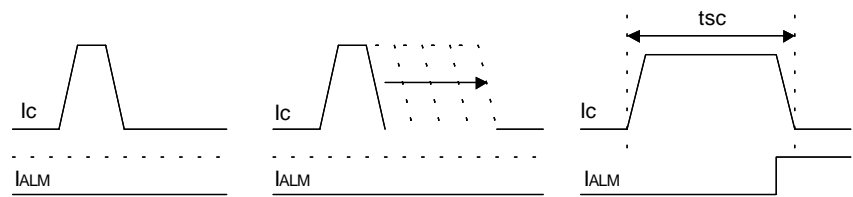


Figure. 4 Definition of tsc

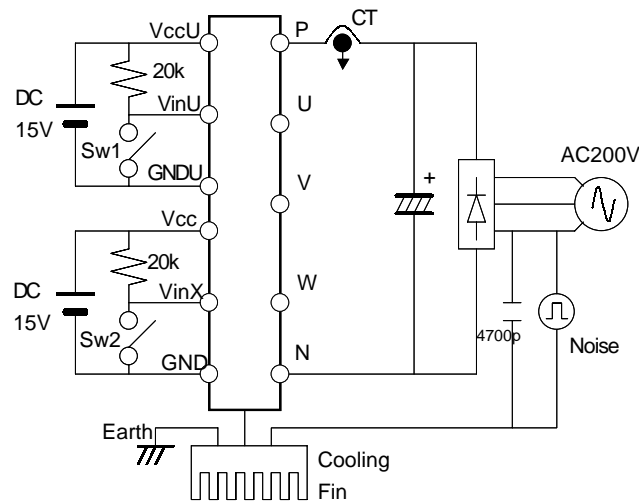


Figure 5. Noise Test Circuit

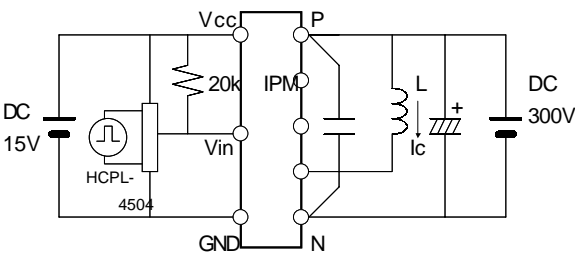


Figure 6. Switching Characteristics Test Circuit

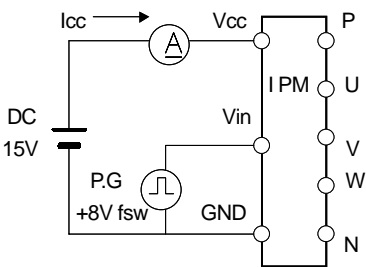
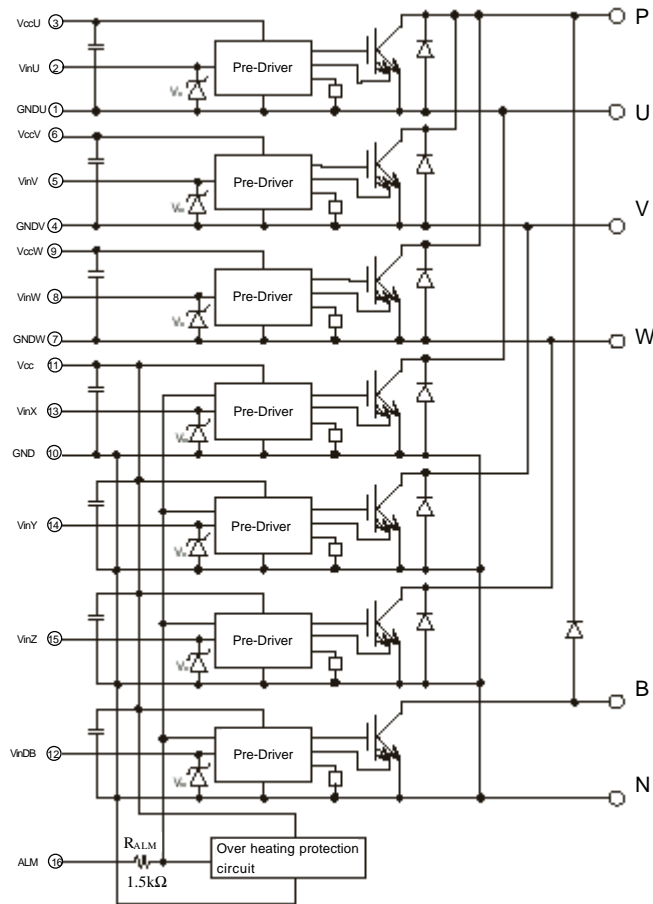


Figure 7. Icc Test Circuit

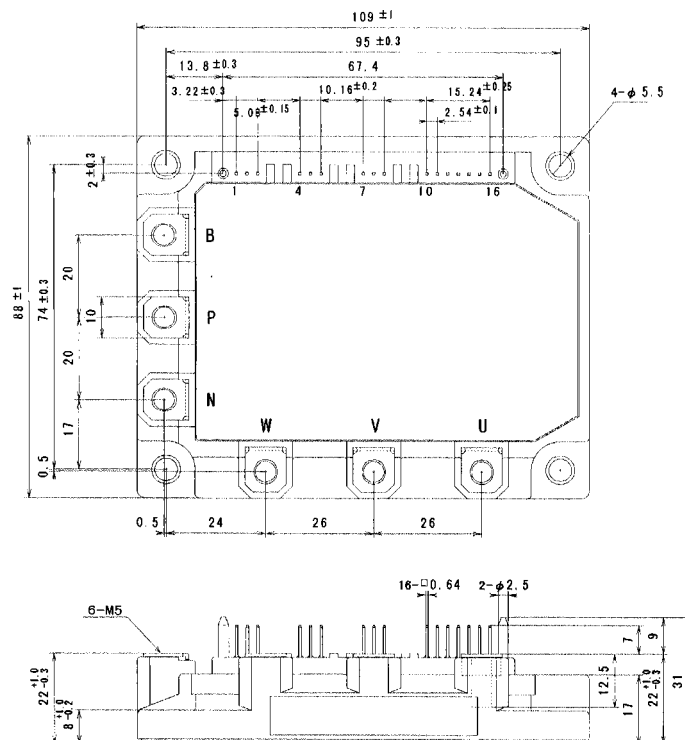
Block diagram



Pre-driver include following functions

- ① Amplifier for drive
- ② Short circuit protection
- ③ Under voltage lockout circuit
- ④ Over current protection
- ⑤ IGBT chip over heating protection

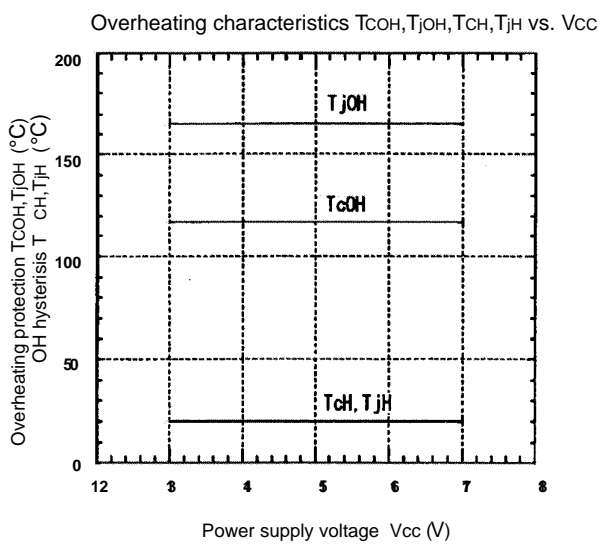
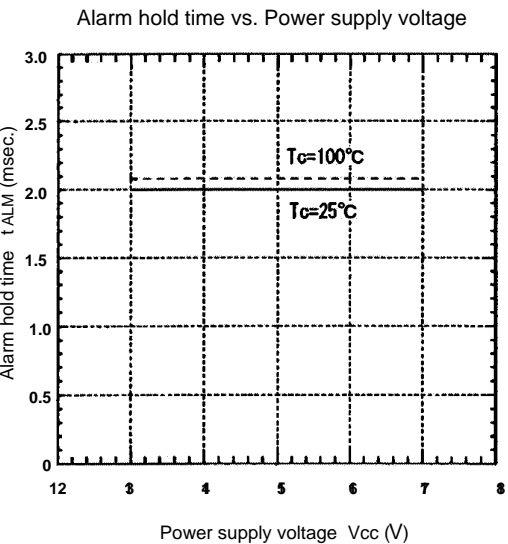
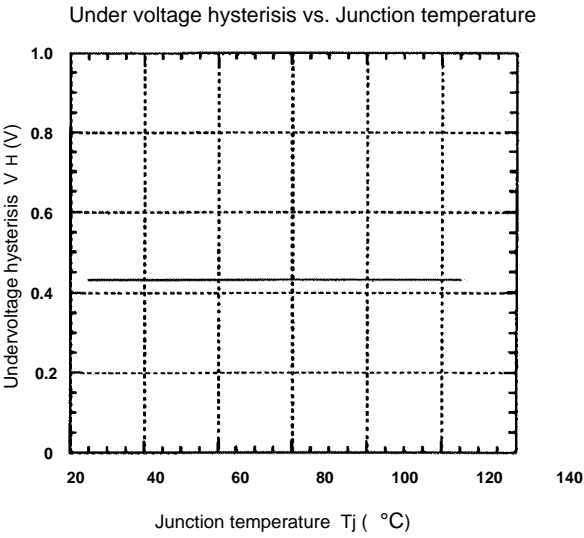
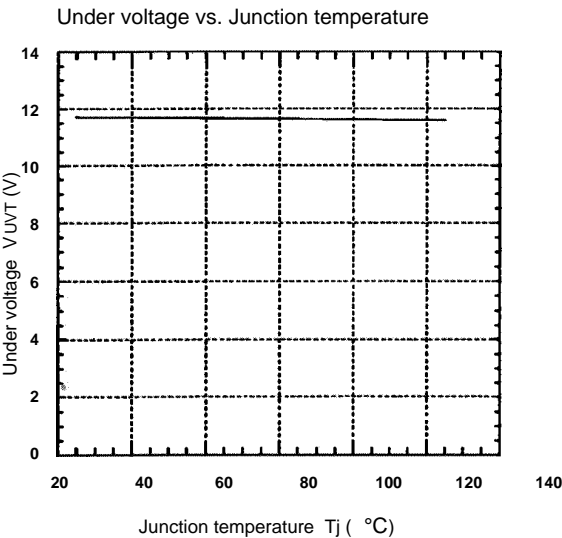
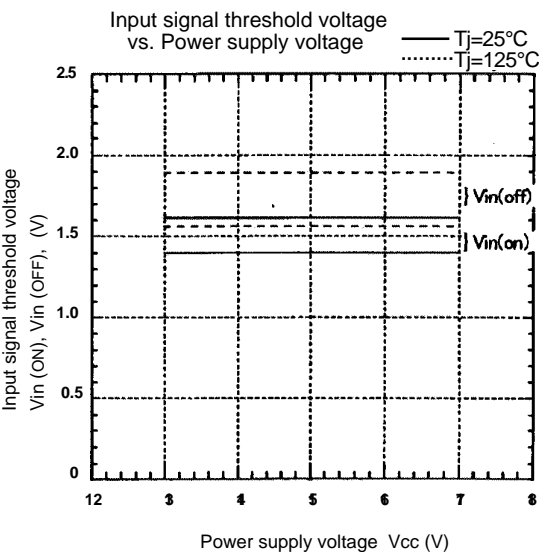
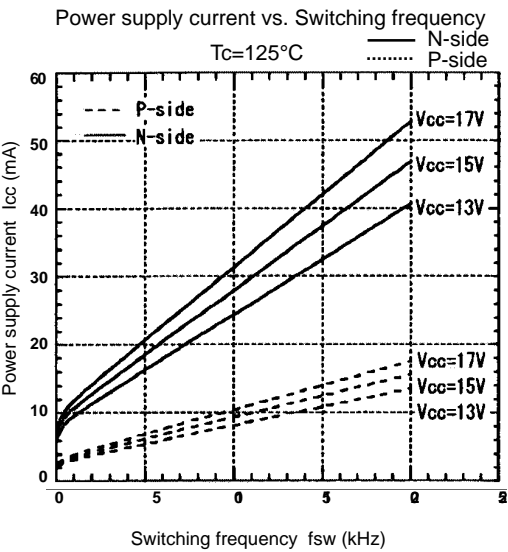
Outline drawings, mm



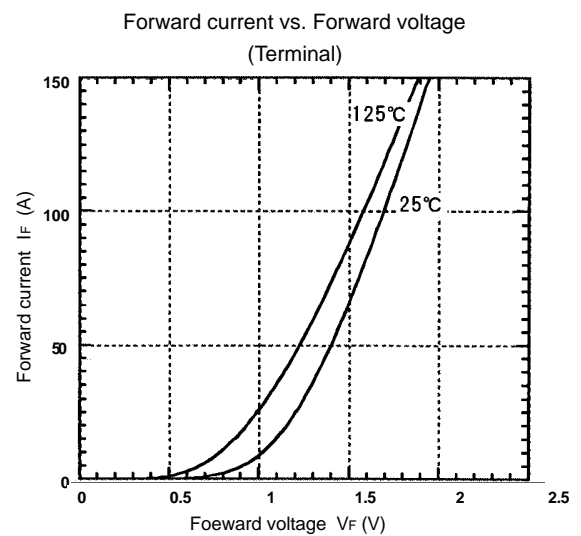
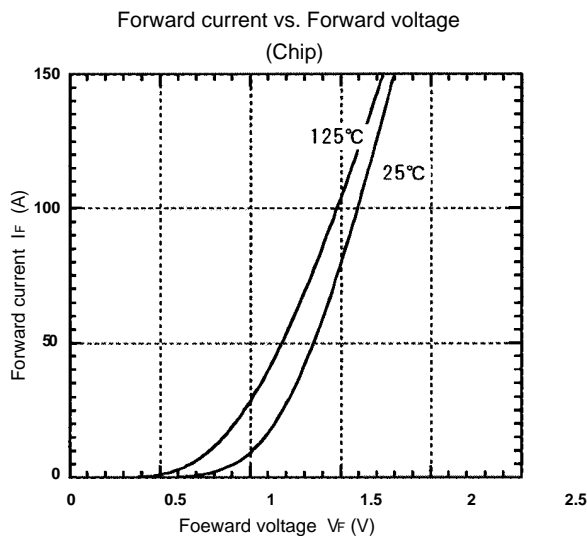
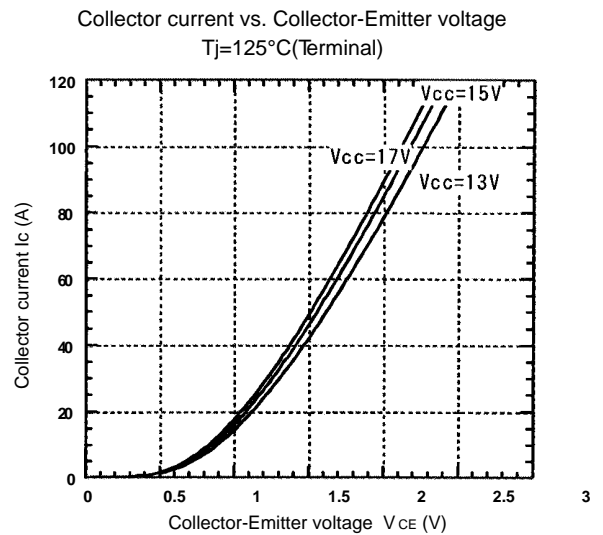
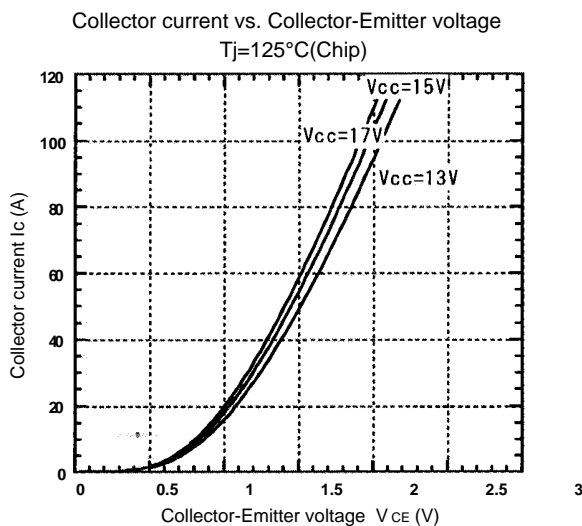
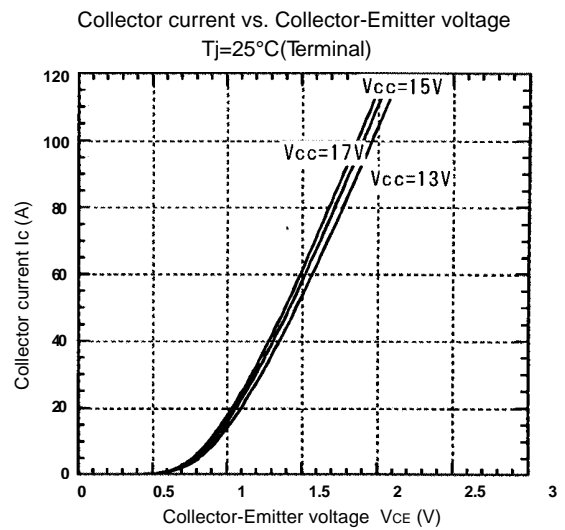
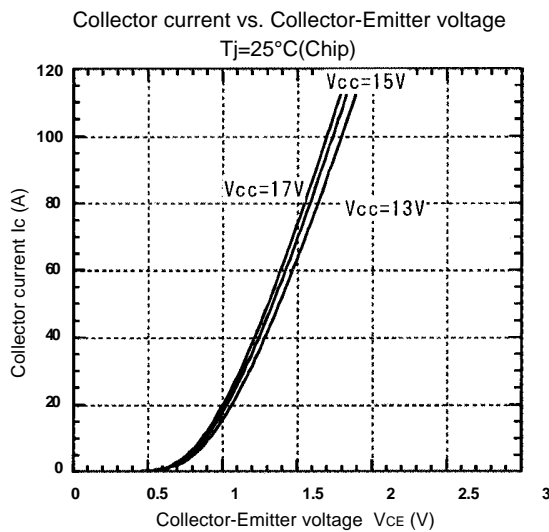
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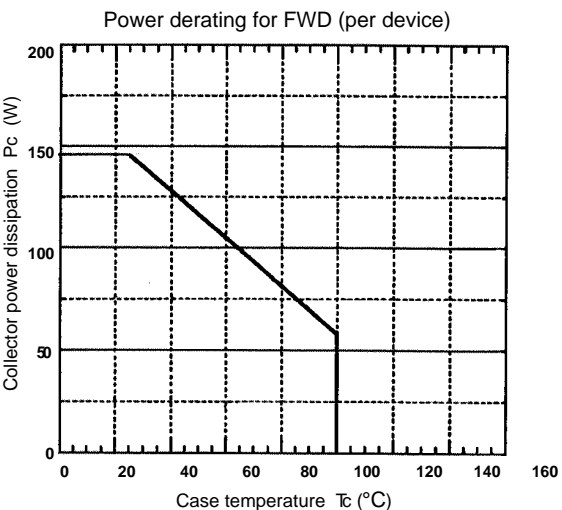
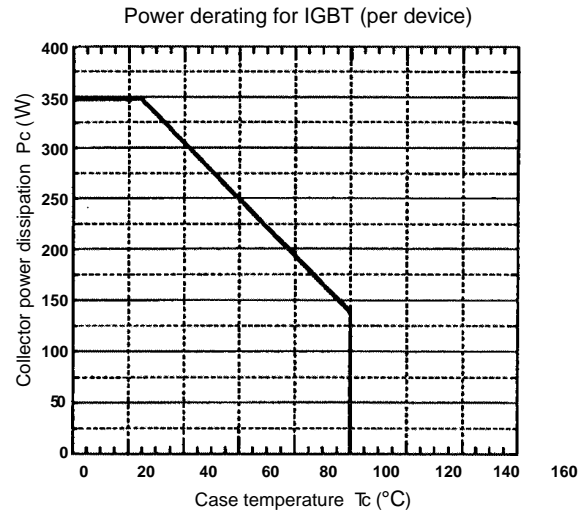
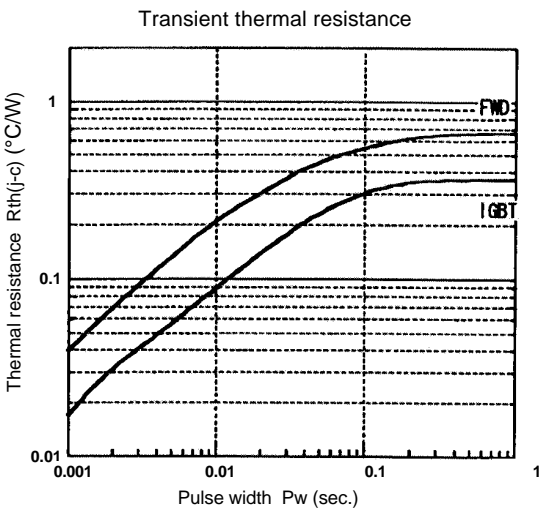
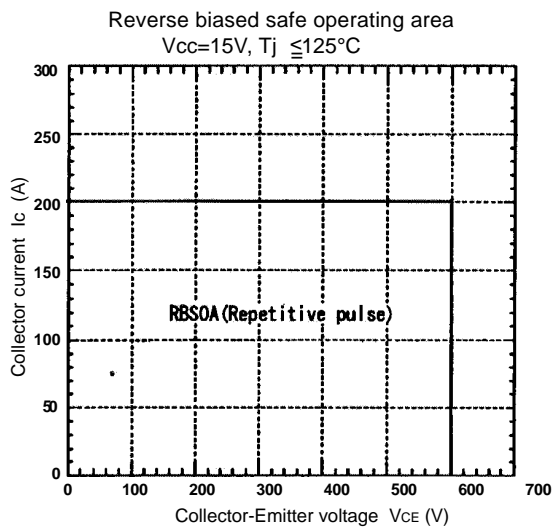
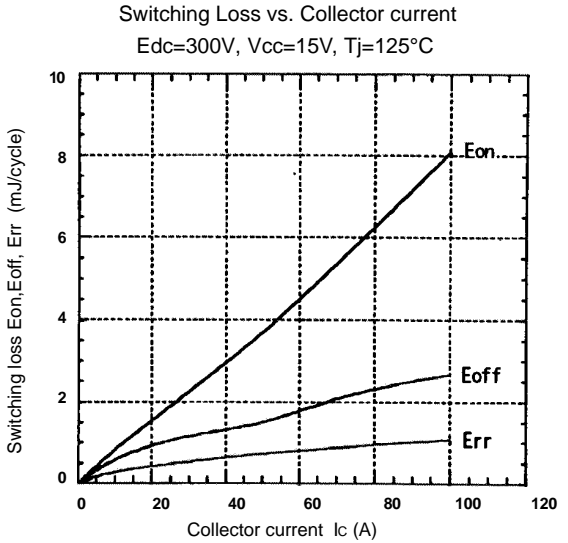
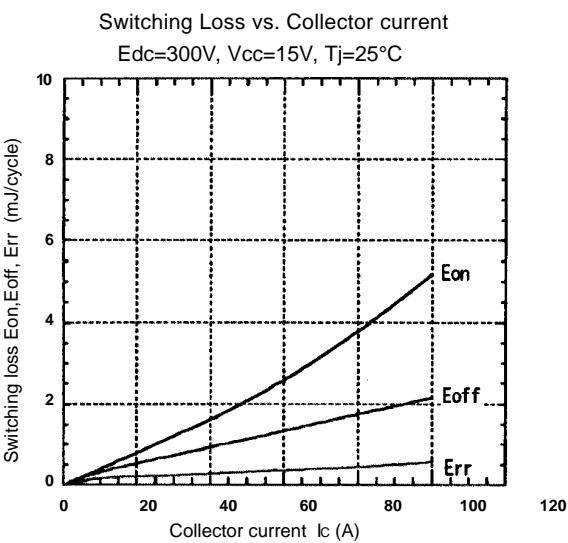
■ Characteristics

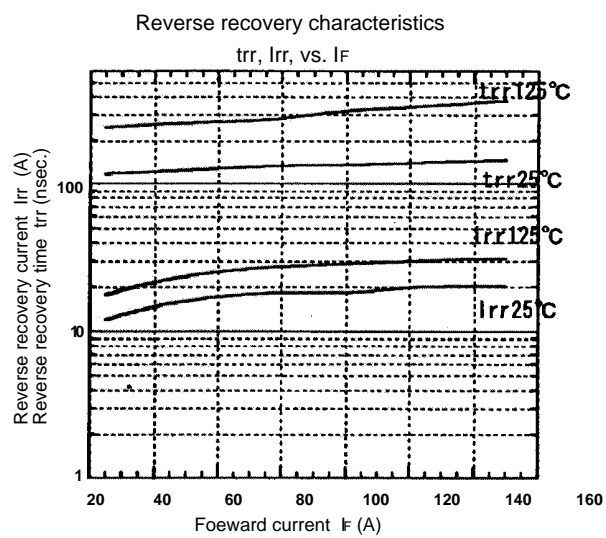
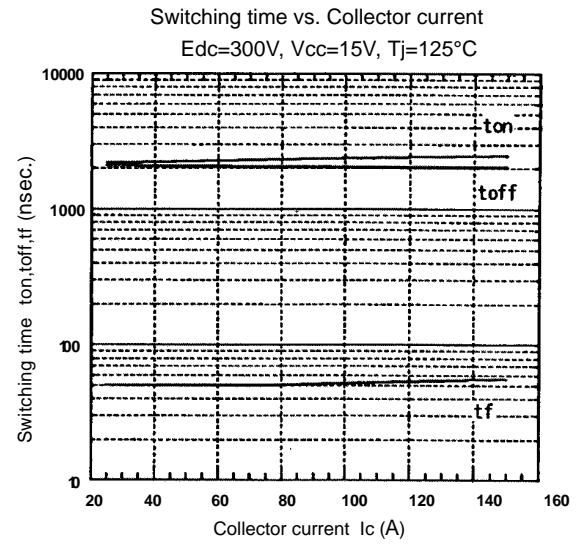
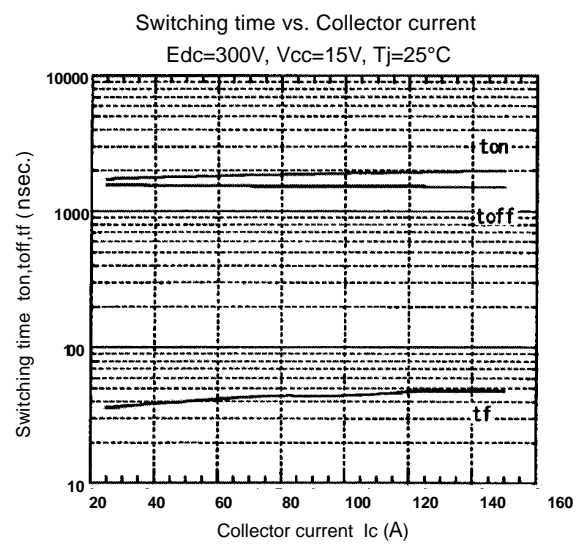
● Control circuit characteristics (Representative)



● Main circuit characteristics (Representative)







● Dynamic brake characteristics (Representative)

